

SuperMOS – SOT23-6L -30V BV_{DSS}, 46mΩ R_{DS(on)}, P-channel MOSFET

1. Description

The AO6405(ES) is P-channel enhancement MOS Field Effect Transistor. Uses advanced trench technology and design to provide excellent R_{DS(ON)} with low gate charge. Device is suitable for use in DC-DC conversion, power switch and charging circuit. Standard Product AO6405(ES) is Pb-free.

2. Features

- -30V, R_{DS(ON)}=46mΩ(TYP.) @V_{GS}=-10V
R_{DS(ON)}=52mΩ(TYP.) @V_{GS}=-4.5V
- Use trench MOSFET technology
- High density cell design for low R_{DS(on)}
- Material: Halogen free
- Reliable and rugged
- Avalanche Rated
- Low leakage current

3. Applications

- PWM applications
- Load switch
- Power management in portable/desktop PCs
- DC/DC conversion

4. Ordering Information

Part Number	Package	Marking	Material	Packing	Quantity per reel	Flammability Rating	Reel Size
AO6405(ES)	SOT23-6L	.6405	Halogen free	Tape & Reel	3,000 PCS	UL 94V-0	7 inches

Table-1 Ordering information

5. Pin Configuration and Functions

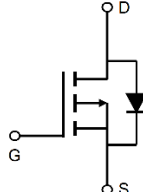
Pin	Function	Outline	Circuit Diagram
1/2/5/6	Drain		
3	Gate		
4	Source		

Table-2 Pin configuration

6. Specification

Absolute Maximum Rating & Thermal Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

Parameter		Symbol	Limit	Unit
Drain-Source Voltage		BV_{DSS}	-30	V
Gate-Source Voltage		V_{GS}	± 20	V
Continuous Drain Current	$T_A = 25^\circ\text{C}$	I_D	-4.7	A
	$T_A = 75^\circ\text{C}$		-3.6	
Maximum Power Dissipation	$T_A = 25^\circ\text{C}$	P_D	2	W
	$T_A = 75^\circ\text{C}$		1.2	
Pulsed Drain Current		I_{DM}	-18.8	A
Operating Junction Temperature		T_J	150	$^\circ\text{C}$
Lead Temperature		T_L	260	$^\circ\text{C}$
Storage Temperature Range		T_{stg}	-55 to 150	$^\circ\text{C}$

Thermal resistance ratings

Single Operation					
Parameter		Symbol	Typical	Maximum	Unit
Junction-to-Ambient Thermal Resistance	$t \leq 10\text{ s}$	$R_{\theta JA}$	47.5	62.5	$^\circ\text{C/W}$
Junction-to-Case Thermal Resistance	Steady State	$R_{\theta JC}$	37	50	

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Electrical Characteristics

At TA = 25°C unless otherwise specified

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
OFF CHARACTERISTICS						
Drain-to-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250uA	-30			V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-30V, V _{GS} =0V			-1	uA
Gate-to-source Leakage Current	I _{GSS}	V _{DS} =0V, V _{GS} =±20V			±100	nA
ON CHARACTERISTICS						
Gate Threshold Voltage	V _{GS(TH)}	V _{GS} =V _{DS} , I _D =-250uA	-1.0	-1.5	-2.0	V
Drain-to-source On-resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-4.7A		46	60	mΩ
		V _{GS} =-4.5V, I _D =-4A		62	80	
Forward Trans conductance	g _{FS}	V _{DS} =-5.0V, I _D =-4.7A			40	S
CHARGES, CAPACITANCES AND GATE RESISTANCE						
Input Capacitance	C _{ISS}	V _{GS} =0V, f=1MHz, V _{DS} =-15V		520		pF
Output Capacitance	C _{OSS}			100		
Reverse Transfer Capacitance	C _{RSS}			65		
Total Gate Charge	Q _{G(TOT)}	V _{GS} =-10V, V _{DS} =-15V, I _D =-4.7A		9.2	11	nC
Threshold Gate Charge	Q _{G(TH)}			4.6	6	
Gate-to-Source Charge	Q _{GS}			1.6		
Gate-to-Drain Charge	Q _{GD}			2.2		
SWITCHING CHARACTERISTICS						
Turn-On Delay Time	t _{d(ON)}	V _{GS} =-10V, V _{DS} =-15V, R _L =3Ω, R _G =3Ω		7.5		ns
Rise Time	t _r			5.5		
Turn-Off Delay Time	t _{d(OFF)}			19		
Fall Time	t _f			7		
BODY DIODE CHARACTERISTICS						
Forward Voltage	V _{SD}	V _{GS} =0V, I _S =-1.0A		-0.7	-1.5	V

7. Typical Characteristic

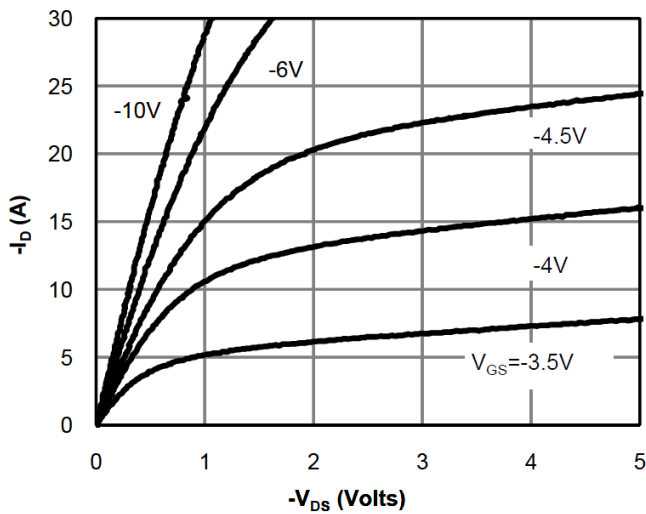


Fig 1: On-Region Characteristics

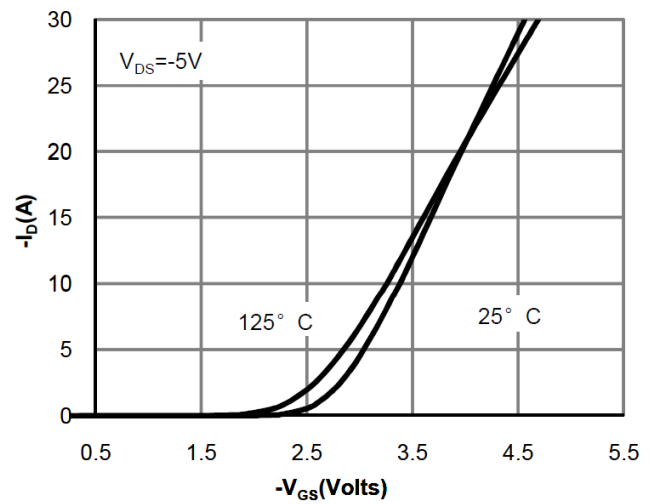


Figure 2: Transfer Characteristics

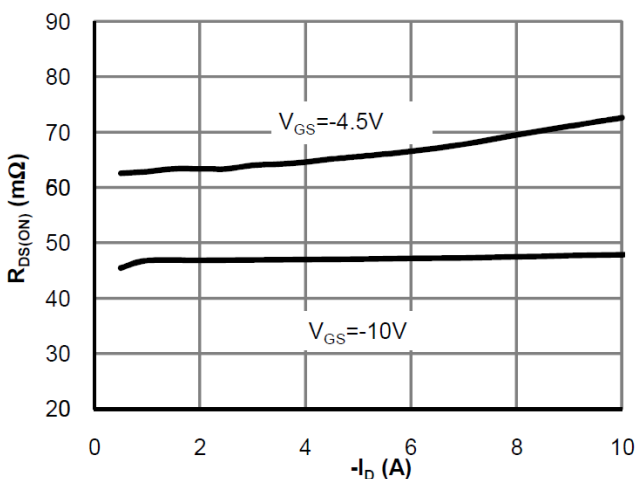


Figure 3: On-Resistance vs. Drain Current and Gate Voltage

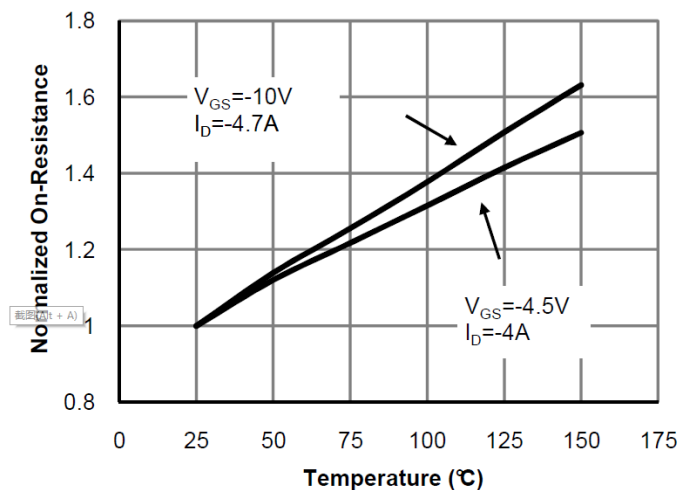


Figure 4: On-Resistance vs. Junction Temperature

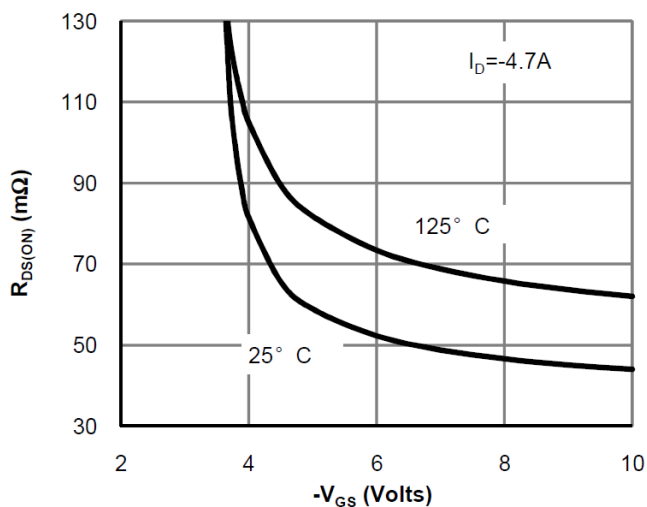


Figure 5: On-Resistance vs. Gate-Source Voltage

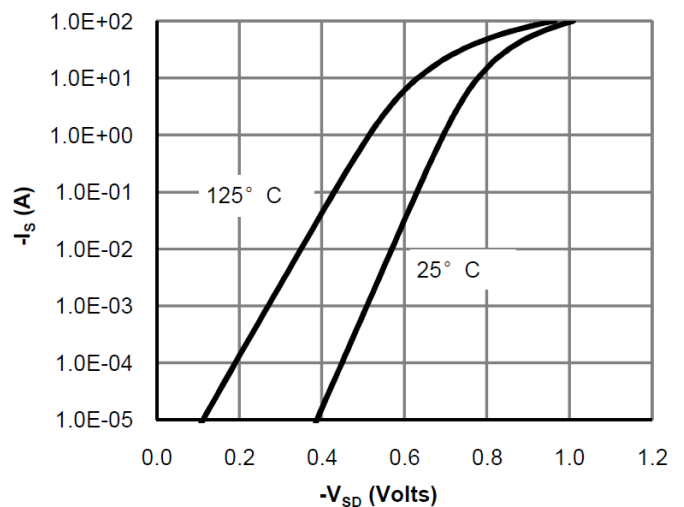


Figure 6: Body-Diode Characteristics

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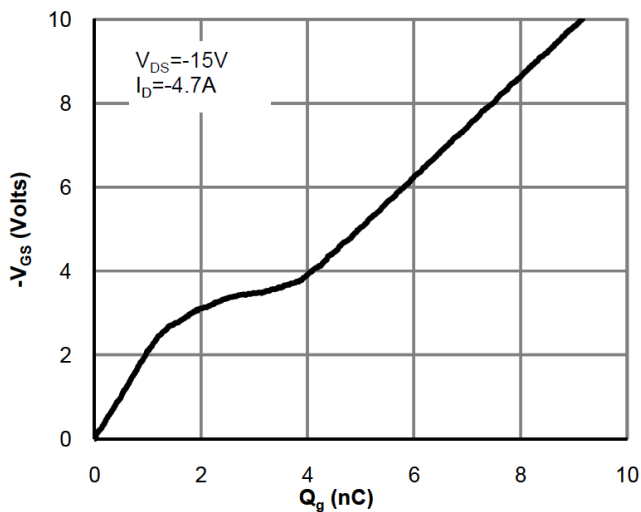


Figure 7: Gate-Charge Characteristics

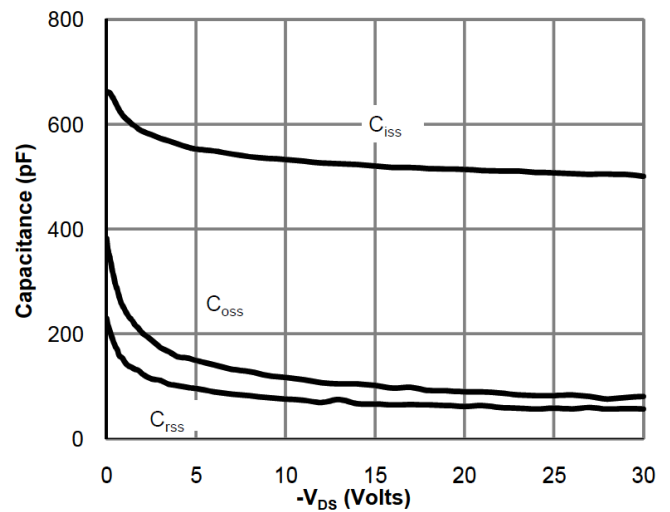


Figure 8: Capacitance Characteristics

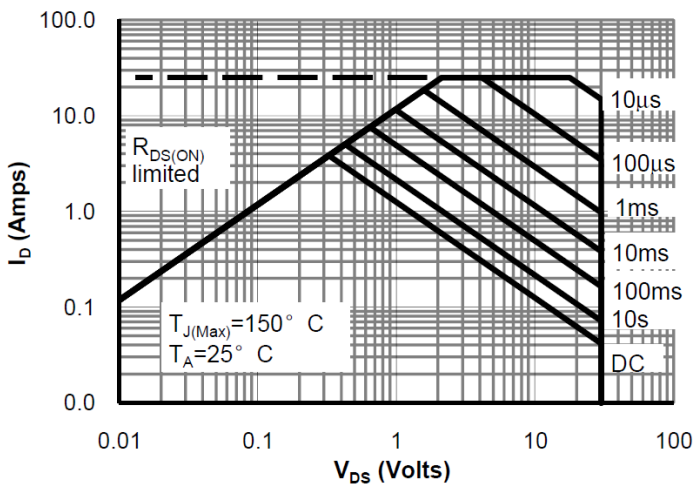


Figure 9: Maximum Forward Biased Safe Operating Area

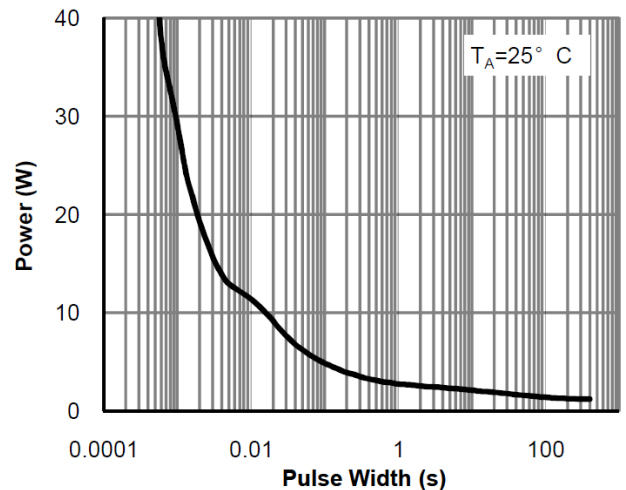
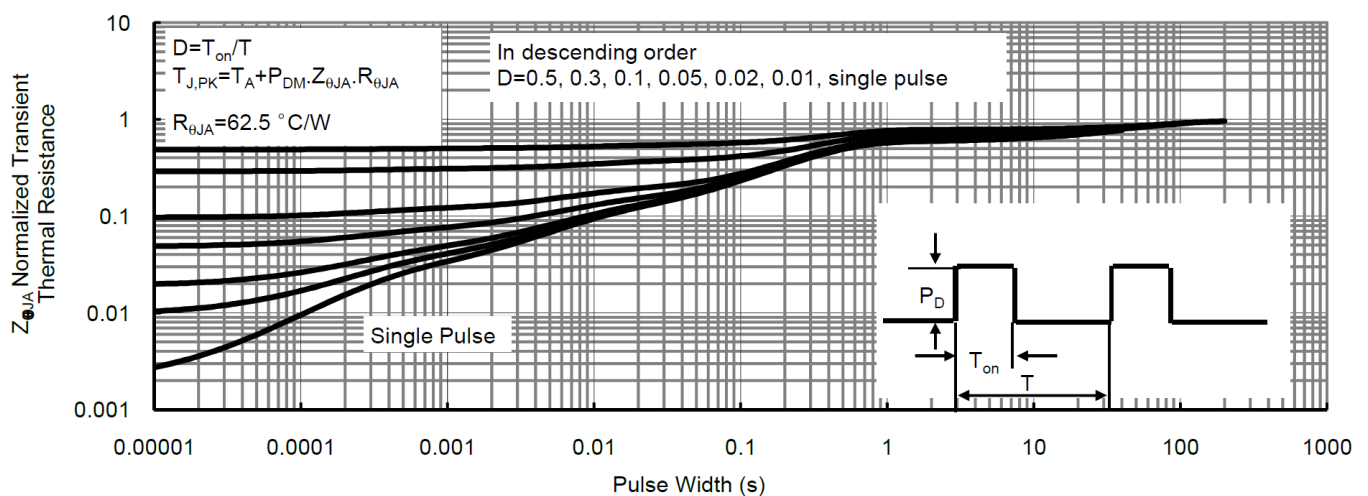
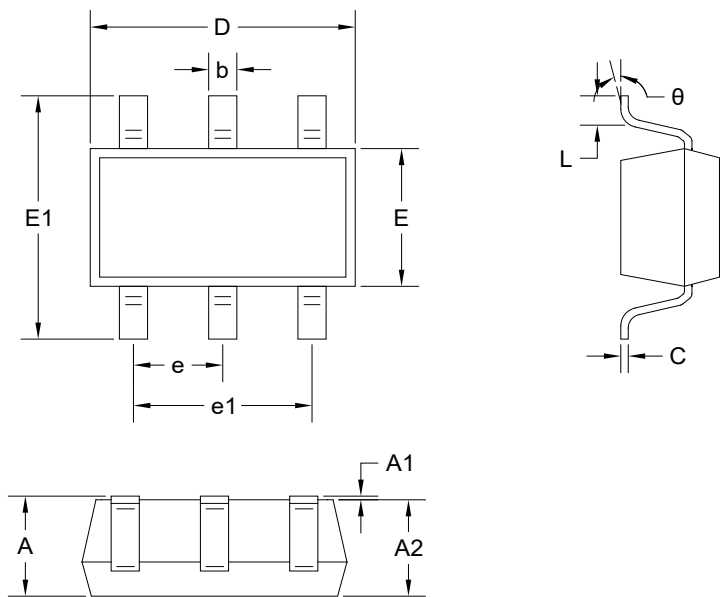


Figure 10: Single Pulse Power Rating Junction-to-Ambient



8. Dimension (SOT23-6L)



Symbol		A	A1	A2	b	c	D
Spec	Min	1.050	0.000	1.050	0.300	0.100	2.820
	Max	1.250	0.100	1.150	0.500	0.200	3.020
Symbol		E	E1	e	e1	L	θ
Spec	Min	1.500	2.650	0.950BSC	1.800	0.300	0°
	Max	1.700	2.950		2.000	0.600	8°

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